

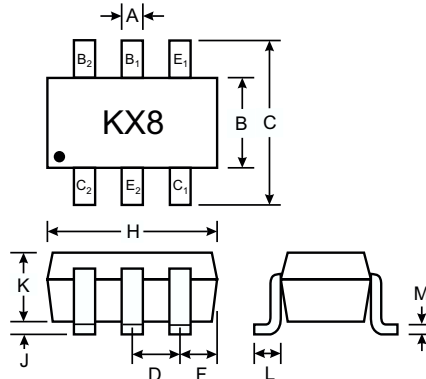
NEW PRODUCT

### Features

- Epitaxial Planar Die Construction
- Complementary PNP Type Available (IMT4)
- Small Surface Mount Package

### Mechanical Data

- Case: SOT-26, Molded Plastic
- Case material - UL Flammability Rating Classification 94V-0
- Terminals: Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Marking: KX8
- Weight: 0.016 grams (approx.)



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
F	—	—	0.55
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
All Dimensions in mm			

### Maximum Ratings @ T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	IMX8	Unit
Collector-Base Voltage	V <sub>CBO</sub>	120	V
Collector-Emitter Voltage	V <sub>CEO</sub>	120	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current - Continuous	I <sub>C</sub>	50	mA
Power Dissipation (Note 1)	P <sub>d</sub>	225	mW
Thermal Resistance, Junction to Ambient (Note 1)	R <sub>θJA</sub>	555	°C/W
Operating and Storage and Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

### Electrical Characteristics @ T<sub>A</sub> = 25°C unless otherwise specified

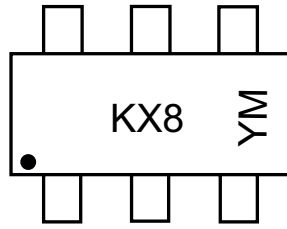
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 2)</b>						
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	120	—	—	V	I <sub>C</sub> = 50μA
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	120	—	—	V	I <sub>C</sub> = 1.0mA
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	5.0	—	—	V	I <sub>E</sub> = 50μA
Collector Cutoff Current	I <sub>CBO</sub>	—	—	0.5	μA	V <sub>CB</sub> = 100V
Emitter Cutoff Current	I <sub>EBO</sub>	—	—	0.5	μA	V <sub>EB</sub> = 4.0V
<b>ON CHARACTERISTICS (Note 2)</b>						
DC Current Gain	h <sub>FE</sub>	180	—	820	—	I <sub>C</sub> = 2.0mA, V <sub>CE</sub> = 6.0V
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	—	—	0.5	V	I <sub>C</sub> = 10mA, I <sub>B</sub> = 1.0mA
<b>SMALL SIGNAL CHARACTERISTICS</b>						
Current Gain-Bandwidth Product	f <sub>T</sub>	—	140	—	MHz	V <sub>CE</sub> = 12V, I <sub>E</sub> = -2.0mA, f = 100MHz

### Ordering Information (Note 3)

Device	Packaging	Shipping
IMX8-7	SOT-26	3000/Tape & Reel

- Notes: 1. Device mounted on FR-5 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes Inc. suggested pad layout AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>. 200mW per element must not be exceeded.  
 2. Short duration test pulse used to minimize self-heating effect.  
 3. For Packaging Details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



KX8 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: N = 2002  
 M = Month ex: 9 = September

Date Code Key

<b>Year</b>	<b>1998</b>	<b>1999</b>	<b>2000</b>	<b>2001</b>	<b>2002</b>	<b>2003</b>	<b>2004</b>
<b>Code</b>	J	K	L	M	N	O	P

<b>Month</b>	<b>Jan</b>	<b>Feb</b>	<b>March</b>	<b>Apr</b>	<b>May</b>	<b>Jun</b>	<b>Jul</b>	<b>Aug</b>	<b>Sep</b>	<b>Oct</b>	<b>Nov</b>	<b>Dec</b>
<b>Code</b>	1	2	3	4	5	6	7	8	9	O	N	D